

MA3D694

Silicon planar type

For high-frequency rectification

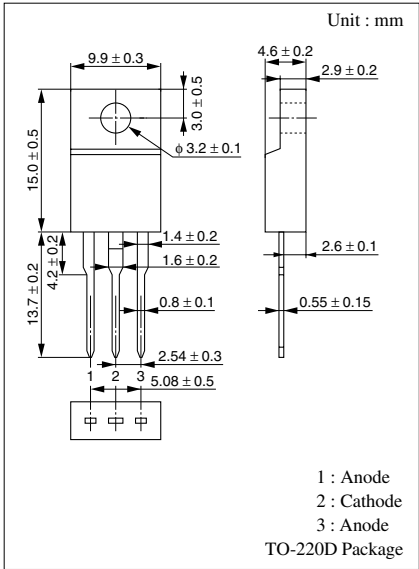
■ Features

- Low forward rise voltage V_F
- Fast reverse recovery time t_{rr}
- TO-220D (Full-pack package) with high dielectric breakdown voltage > 5.0 kV
- Easy-to-mount, caused by its V cut lead end

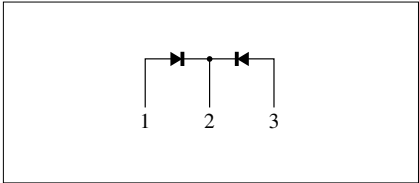
■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Repetitive peak reverse voltage	V_{RRM}	400	V
Non-repetitive peak reverse surge voltage	V_{RSM}	400	V
Average forward current	$I_{F(AV)}$	10	A
Non-repetitive peak forward surge current*	I_{FSM}	60	A
Junction temperature	T_j	-40 to +150	$^\circ\text{C}$
Storage temperature	T_{stg}	-40 to +150	$^\circ\text{C}$

Note) *: Half sine-wave; 10 ms/cycle



Internal Connection



■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Repetitive peak reverse current	I_{RRM1}	$V_{RRM} = 400$ V, $T_C = 25^\circ\text{C}$			50	μA
	I_{RRM2}	$V_{RRM} = 400$ V, $T_j = 150^\circ\text{C}$			6	mA
Forward voltage (DC)	V_F	$I_F = 5$ A, $T_C = 25^\circ\text{C}$			1	V
Reverse recovery time*	t_{rr}	$I_F = 1$ A, $I_R = 1$ A			100	ns
Thermal resistance	$R_{th(j-c)}$	Direct current (between junction and case)			3	$^\circ\text{C/W}$
	$R_{th(j-a)}$				62.5	$^\circ\text{C/W}$

Note) 1. Rated input/output frequency: 10 MHz

2. *: t_{rr} measuring circuit

